



Low power Battery fuel gauge IC for Li-ion battery

# MM8118G01RFE

#### **Outline**

MM8118 is a high accuracy battery monitoring IC for Li-ion battery and Li-polymer battery. This IC measures temperature, voltage, and current with high-precision delta-sigma AD converter, integrates current value both at discharging and charging, and performs capacitance correction based on the measurement value and specific battery characteristics parameter. Thus the IC achieves excellent management ability for battery power.

MM8118 provides several features to make battery use safe and secure. Battery degradation detection which is based on capacitance change is available. And this IC has features for notification of these information.

MM8118 can be implemented at both of host-side and battery-side.

### **Features**

· High accuracy current/voltage measurement

Current and voltage value are measured by high accuracy 16bit delta-sigma AD converter. The current resolution is 1mA and the voltage resolution is 1mV.

· High accuracy battery power management

Battery power is based on integration of periodically-measured current and the value is corrected with open voltage(OCV) and battery characteristics parameters. The battery power is managed so as to minimize the error constantly.

· Battery degradation monitor

Battery total capacitance is measured periodically and status of capacitance change is monitored.

#### Package type

PLP-12A

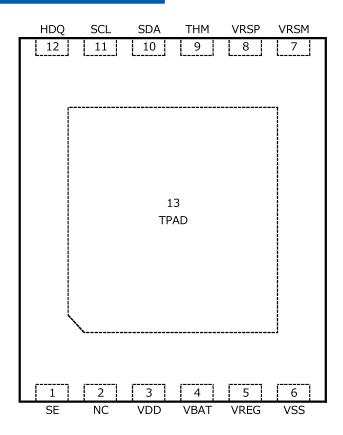


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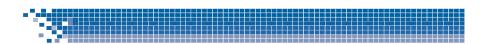
## Pin configuration



## **Terminal explanations**

PIN No.	IN/OUT	SYMBOL	FUNCTION
1	OUT	SE	General purpose output pin
2	-	NC	Not Supported
3	-	VDD	Power supply pin
4	IN	VBAT	Voltage sensor input pin
5	OUT	VREG	Regulator output pin
6	-	VSS	Power supply pin
7	IN	VRSM	Current sensor input pin
8	IN	VRSP	Current sensor input pin
9	IN	THM	Thermistor input
10	IN/OUT	SDA	I2C data input/output pin
11	IN/OUT	SCL	I2C clock input/output pin
12	OUT	HDQ	General purpose output pin
13	-	TPAD	Exposed Pad It is recommended to connect to the ground plane.





## **Absolute Maximum Ratings**

(Ta=25℃, unless otherwise specified)

ITEM	SYMBOL	MIN.	MAX.	UNIT
Supply voltage	VDD	-0.3	6.0	٧
Input voltage	VIN	-0.3	6.0	٧
Input voltage to CE	VIN2	-0.3	VDD+0.3	٧
Input voltage to THM	VIN3	-0.3	VDD+0.3	٧
Regulator terminal voltage	VREG	-0.3	2.2	٧
Regulator terminal voltage for thermistor	TREG	-0.3	2.2	٧
Input voltage to VRSM and VRSP	VI	-0.3	2.2	>
Storage temperature	Tstg	-40	125	ပ

## **Recommended Operating Conditions**

ITEM	SYMBOL	MIN.	MAX.	UNIT
Operating ambient temperature	Topr	-20	85	$\mathbb{C}$
Operating voltage	Vop	2.5	5.5	٧





## **Electrical characteristics**

(Unless otherwise specified, Vdd=3.6V,Topr=25℃)

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNIT	*1
Normal mode			-	30.5	-	μА	
current consumption	Inor	*2	-	35.0	-		T1
		Topr= <b>-</b> 20∼85℃ *2	22.0	ı	57.0		
Sleep mode current consumption	Islp	Interval 20s	-	21.8	-	μА	
		Interval 20s *2	-	22.0	-		T1
		Interval 20s Topr=-20∼85℃ *2	11.0	-	33.0		
STANDBY mode	Istb		-	6.0	-	- μΑ	T1
current consumption	ISLD	Topr= <b>-</b> 20∼85℃	2.0	-	20.0		
Shutdown mode current consumption	Isdn		0.2	0.36	1.0	μА	T1

<sup>\*1</sup> The test circuit symbols.

<sup>\*2</sup> In case of use THM ( $10k\Omega$ )



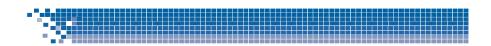


(Ta=25℃, unless otherwise specified)

			-	,			11007
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNIT	*3
Supplied voltage	VDD		2.5	-	5.5	٧	-
(SCL,SDA,HDQ) Data I/O pin voltage range	VIO		-0.3	ı	VDD+0.3	٧	-
Oscillation frequency 1	fosc1	Ta=-20∼85℃	-	2000.0	1	kHz	T2
Oscillation frequency 2	fosc2	Ta= <b>-</b> 20∼85℃	-	32.768	-	kHz	T2
Current sensor input range	Irng		-48.0	ı	48.0	mV	ТЗ
Battery voltage sensor input range	Vrng		1800	I	5000	mV	ТЗ
Internal Temperature sensor input range	Trng		-20	-	85	°C	ТЗ
THM pin internal resistance	Pthm		_	10.0	1	kΩ	ТЗ
Regulator voltage	Vreg	VDD=3.6V @25℃	1.76	1.8	1.84	٧	T4
VBAT input impedance	Pcell	VBAT=3.6V	2.0	3.5	-	МΩ	T5
Reset detecting voltage	Vrst	design assurance	1.7	1.9	2.1	٧	-
Reset hysteresis voltage	Vrhys	design assurance	0.10	0.15	0.20	٧	-

<sup>\*3</sup> The test circuit symbols.



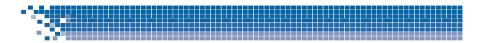


I2C/IO interface characteristics : Characteristics of the SDA and SCL I/O stages.

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNIT	*4
Low level input voltage	VIL		-0.3	-	0.6	٧	Т8
High level input voltage	VIH		1.2	-	VDD+0.3	٧	Т8
(SCL, SDA) Input voltage hysteresis	Vhys		0.1	-	-	٧	Т8
SCL, SDA,HDQ Low Level output voltage	Vol1	Iol=3mA	-	-	0.4	٧	Т6
SE output Low level voltage	Vol2	Iol=3mA	-	-	0.4	٧	Т6
SE output High level voltage	Voh	Ioh=1mA	VDD-0.5	-	VDD	<b>V</b>	Т6
SCL,SDA Pulse width of spikes suppressed by input filter	tsp		50	-	-	ns	Т8
Input current each I/O pin	Ii	input voltage between 0.1 and 0.9 VCCmax	-10	-	10	mA	T7
Capacitance for each I/O pin	Ci		-	-	10	pF	Т8

<sup>\*4</sup> The test circuit symbols.





I2C interface characteristics: Characteristics of the SDA and SCL bus lines

All values referred to VIHmin and VILmax levels

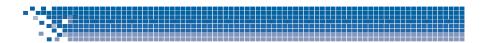
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNIT	*5
SCL clock frequency	fSCL		0	-	400	kHz	Т8
Hold time START condition	tHD:STA		0.6	-	-	ms	Т8
Low period of SCL clock	tLOW		1.3	-	-	ms	Т8
High period of SCL clock	tHIGH		0.6	-	-	ms	T8
Setup time for a repeated START condition	tSU:STA		0.6	-	-	ms	Т8
Data hold time	tHD:DAT	for I2C-bus devices	0	- -	- (*6)	ms	Т8
Data set-up time	tSU:DAT		100 (*7)	-	-	ns	Т8

- \*5 The test circuit symbols.
- \*6 The maximum tHD;DAT has only to be met if the device does not stretch the LOW period (tLOW) of the SCL signal.
- \*7 A Fast-mode I2C-bus device can be used in a Standard-mode I2C-bus system, but the requirement tSU;DAT ≥ 250 ns must then be met. This will automatically be the case if the device does not stretch the LOW period of the SCL signal. If such a device does stretch the LOW period of the SCL signal, it must output the next data bit to the SDA line tr max + tSU;DAT = 1000 + 250 = 1250 ns (according to the Standard-mode I2C-bus specification) before the SCL line is released.

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNIT	*8
Fall time of SDA signals	tF	Iol= 3mA	-	-	300	ns	Т8
Setup time for STOP condition	tSU:STO		0.6	-	-	ms	Т8
Bus free time between a STOP and START condition	tBUF		1.3	ı	1	ms	Т8
Capacitive load for each bus line	Cb		-	-	400	pF	Т8

<sup>\*8</sup> The test circuit symbols.





### **Function**

MM8118 measures current, voltage, and temperature periodically, and monitors the remaining capacity and condition of a lithium ion battery.

#### **FUEL GAUGE**

By periodical current measurement, this IC recognizes charge / discharge current flow and integrates charge / discharge current. And it also manages the battery capacity which remains (remaining capacity).

It is possible to get useful information which is operation time (usable time) on the basis of such managed capacity.

However, since this IC may accumulate few errors for a long time even if it integrates current measured by high accuracy  $\Delta\Sigma$ ADC, it has a function which correct the remaining capacity from the measurement voltage in the state (OCV), when the specific conditions were satisfied.

Correction of remaining capacity by OCV

From the measured voltage at the state when the specific conditions were satisfied, and the characteristic data of the battery which were saved in the built-in memory, the correction of the remaining capacity by open voltage (OCV) is performed the calculation of the ideal remaining capacity, and is corrected the difference with the present remaining capacity.

The above-mentioned remaining capacity correction is performed when the following all conditions are satisfied.

- 1) The measurement current is less than a threshold value
- 2) The specific time passed which the return voltage is stable after charge and discharge
- 3) The measurement temperature is less than a threshold value
- 4) The threshold time passes after the remaining capacity was corrected





### **Battery Capacity**

The battery capacity is defined as the maximum capacity of the battery usable range for this IC.

Battery capacity decreases gradually with prolonged use.

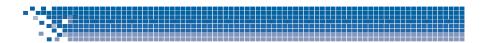
Then, when the specific conditions are satisfied, this IC performs the calculation of the battery capacity, and applies the calculation result to the present battery capacity.

alculation condition of battery capacity

- 1) Charge is performed more than a threshold capacity until more than the specified voltage
- 2) OCV measurement is performed before Charge start and after Charge end

Since the device calculates the ratio of change (capacity degradation rate) from initial battery capacity at updating, it is possible to refer it with the judgment of battery degradation.

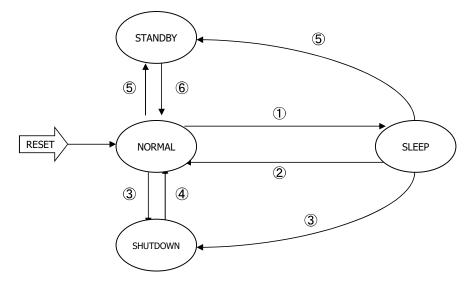




#### POWER MANAGEMENT

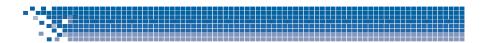
In this IC which manages the remaining capacity and monitors the condition of lithium ion battery, it is an important point to reduce the power consumption.

The operational mode diagram and each mode description are shown below.



- ① The specific time is passed in state which the measured current is less than threshold value. Receiving the command to SLEEP mode change.
- ② The measured current is more than threshold value. Receiving the command to NORMAL mode change.
- ③ Battery voltage is less than low limit voltage of IC when SHUTDOWN setting of Control Status is 1.
  Receiving the command to SHUTDOWN mode change.
- ④ Input the command with selected slave address on I2C communication.
- Sattery voltage is less than low limit voltage of IC when HIBERNATE setting of Control Status is 1.Receiving the command to STANDBY mode change.
- 6 Receiving I2C command.





#### NORMAL mode

Current, voltage, and temperature are measured, and the management of remaining capacity are performed.

Measurement / processing cycle is performed in a cycle of 1 second (Default). I2C communication is always in valid state.

#### Mode Change condition

<ul> <li>Mode change command is received</li> </ul>	$\rightarrow$	Each requested mode
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#### SLEEP mode

Current, voltage, and temperature are measured, and the management of remaining capacity are performed.

Measurement / processing cycle is performed in a cycle of 20 seconds (Default). I2C communication is always in valid state.

#### Mode Change condition

- $\cdot$  Mode change command is received ightarrow Each requested mode
- $\cdot$  The measured current is more than threshold value ightarrow NORMAL mode

### STANDBY mode

In STANDBY mode, fuel gauge processing stops. Volatile RAM contents are maintained. And, all registers are maintained.

To exit from STANDBY mode, host send any I2C command.

Mode Change condition

I2C command is received.  $\rightarrow$  NORMAL mode





#### SHUTDOWN mode

In SHUTDOWN mode, all activity stops, and volatile RAM contents are lost.

All registers are lost.

When the IC exits from SHUTDOWN mode, power-on-reset occurs and then the IC enter NORMAL mode.

Mode Change condition

Input the command with selected slave address on I2C communication.

→ NORMAL Mode via POR

Protection Function

If VBAT terminal voltage becomes higher than the overvoltage detection threshold, this IC detects overvoltage condition. When SE terminal is configured this function, the terminal turns to Hi level, and it is available to notify to main unit or to control external circuit. The overvoltage detection / recover voltage and the overvoltage delay time are able to set respectively.

Remaining Capacity Notification Function

The IC is able to output interrupt from HDQ terminal and to notify to the system which the remaining capacity is over the threshold.

It has two kind of notified thresholds which are the discharge threshold and charge threshold. The interrupt is generated when the remaining capacity is below the discharge threshold during discharging and is over the charge threshold during charging.

Those thresholds are able to set by command, and the interrupt is cleared by setting the value.

**ALERT Function** 

An alert interrupt can be output for a host, depending on a state of Flags (\*9). This alert interrupt is output by HDQ or SE. (\*9: see Flags command section) The condition to produce an alert interrupt, the selection of output signal and the polarity setting can be set in built-in NVM.

When an alert interrupt occurs, HDQ or SE output is asserted. The factor of alert interrupt are known in Flags. The alert interrupt is negated when the alert factors are cleared.





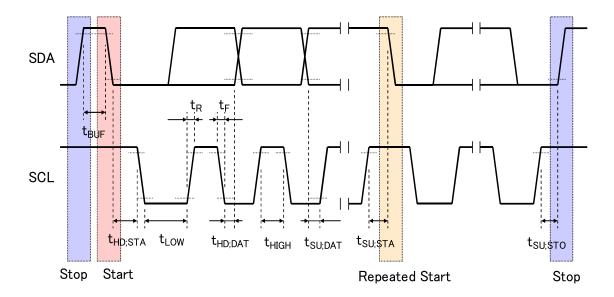
### **I2C Correspondence**

I2C correspondence is used for data transfer between IC and MCU. Communicate data in reference to I2C specification.

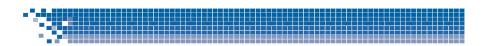
### TIMING CHART

Timing chart of I2C correspondence is depicted below.

Please refer to "ELECTRICAL CHARACTERISTICS" for symbols described in schematic.

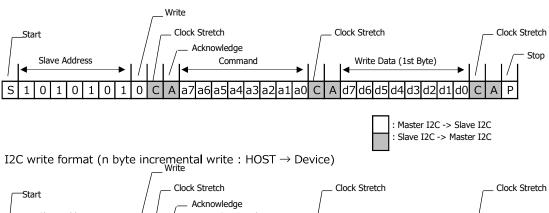


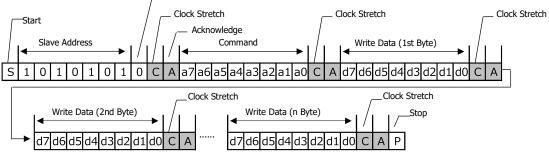




### CORRESPONDENCE FORMAT

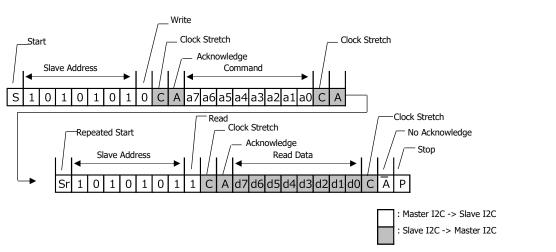
I2C write format (1 byte write :  $HOST \rightarrow Device$ )





: Master I2C -> Slave I2C : Slave I2C -> Master I2C

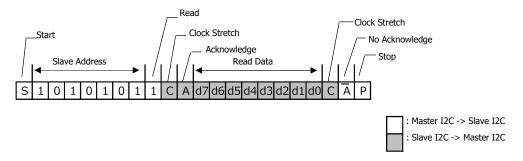
I2C read format (1 byte read : Device  $\rightarrow$  Host)



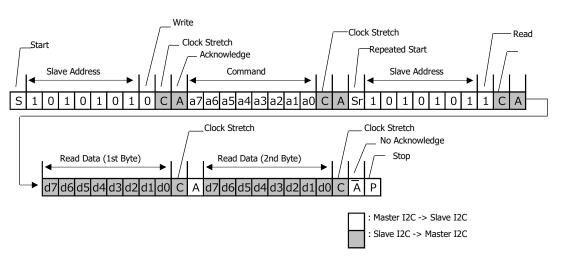
Oct, 2020 Rev.0



I2C quick read format (1 byte read : Device → Host)



I2C read format (n byte incremental read : Device  $\rightarrow$  Host)



### **I2C DEVICE ADDRESS**

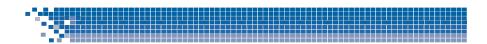
The default of the device address is AA/AB.

The device address is recorded in internal NVM and is loaded at power-on. The I2C device address can be set to arbitrary value indicated by customer's request on our mass production line.

#### **I2C TIMEOUT**

MM8118 processes time-out in 0.2 second (Default) when it receives no reply from the host or I2C bus is continuously hold during I2C communication by the host. After time-out, the executing request is aborted and MM8118 will be ready condition of I2C protocol. The settings of time-out value is stored in internal NVM and are modifiable.

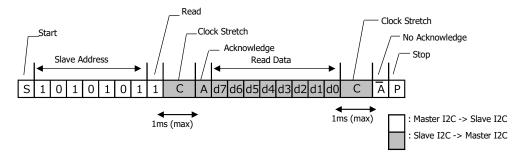




### I2C CLOCK STRETCH

MM8118 needs clock stretch for I2C communication with host device. Maximum period of clock stretch is 1ms.

I2C quick read format (1 byte read : Device  $\rightarrow$  Host)



#### **I2C WAIT TIME**

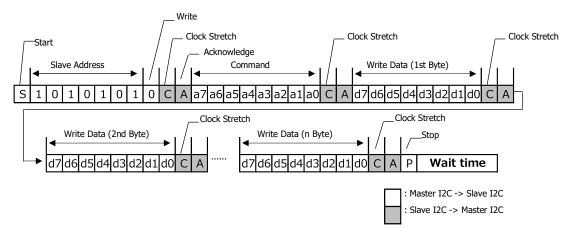
MM8118 may require a wait time from the completion of I2C Write format to next start of I2C communication. (Bus free time between a STOP and START condition)

In case of the following command, the MM8118 needs the wait time for long.

Table 11-1. Command List of Wait time

Code	Name	Wait time
0x00/0x01	Control (Reset request)	
0x60	Block Data Checksum	100msec
0x54	Authenticate Checksum	

I2C write format (n byte write :  $HOST \rightarrow Device$ )



If the host sends I2C command without appropriate wait time, MM8118 will return Nack response.





## Command

#### **COMMAND SUMMARY**

This IC uses the command shown below to get various measurement information, and to setup operational mode.

Table 12-1. Standard Command List

Name	Code	R/W	Data size	Unit
Control	0x00/0x01	R/W	2	N/A
At Rate	0x02/0x03	R/W	2	mA
Unfiltered SOC	0x04/0x05	R	2	%
Temperature	0x06/0x07	R	2	0.1K
Voltage	0 x 08/0x09	R	2	mV
Flags	0x0A/0x0B	R	2	N/A
Nominal Available Capacity	0x0C/0x0D	R	2	mAh
Full Available Capacity	0x0E/0x0F	R	2	mAh
Remaining Capacity	0x10/0x11	R	2	mAh
Full Charge Capacity	0x12/0x13	R	2	mAh
Average Current	0 x 14/0x15	R	2	mA
Average Time To Empty	0x16/0x17	R	2	minutes
Filtered FCC	0x18/0x19	R	2	mAh
Safety Status	0x1A/0x1B	R	2	N/A
Unfiltered FCC	0x1C/0x1D	R	2	mAh
Max Load Current	0x1E/0x1F	R	2	mA
Unfiltered RM	0x20/0x21	R	2	mAh
Filtered RM	0x22/0x23	R	2	mAh
BTP SOC1 Set	0x24/0x25	R/W	2	mAh
BTP SOC1 Clear	0x26/0x27	R/W	2	mAh
Internal Temperature	0x28/0x29	R	2	0.1K
Cycle Count	0x2A/0x2B	R	2	Counts
State Of Charge	0x2C/0x2D	R	2	%
State Of Health	0x2E/0x2F	R	2	%
Charge Voltage	0x30/0x31	R	2	mV
Charge Current	0x32/0x33	R	2	mA
Passed Charge	0x34/0x35	R	2	mAh
DOD0	0x36/0x37	R	2	N/A
Self Discharge Current	0x38/0x39	R	2	mA





Table 12-2. Extended Command List

Name	Code	R/W	Data size	Unit
Pack Config	0x3A/0x3B	R	2	N/A
Design Capacity	0x3C/0x3D	R	2	mAh
Data Flash Class	0x3E	R/W	1	N/A
Data Flash Block	0x3F	R/W	1	N/A
Block Data / Authenticate	0x40~0x53	R/W	20	N/A
Block Data / Authenticate Checksum	0x54	R/W	1	N/A
Block Data	0x55~0x5F	R/W	11	N/A
Block Data Checksum	0x60	R/W	1	N/A
Block Data Control	0x61	R/W	1	N/A
Product Information Length	0x62	R	1	N/A
Product Information	0x63~0x6C	R	10	N/A
FG Condition	0x6E/0x6F	R/W	2	N/A
Reserved	0x70/0x71	-	-	-
Current	0x72/0x73	R	2	mA
Reserved	0x74~0x7F	-	_	-





### STANDARD COMMAND DETAIL (Group1)

The commands which response data size is 2 bytes are shown below.

Unfiltered SOC [0x04/0x05]

This command returns the percentage of usable unfiltered capacity to usable unfiltered full charge capacity based on temperature and discharge current. If no current flows or charge current flows, it returns the percentage which based on defined discharge (about 0.2C).

Data Type : unsigned integer

Unit : [%]

Temperature [0x06/0x07]

This command returns the temperature information measured from the external thermistor input or measured by the temperature sensor built in this IC.

Data Type : signed integer

Unit : [0.1K] ( $[0.1^{\circ}C]$  selectable by Data Flash setting)

Voltage [0x08/0x09]

This command returns the voltage of a battery or a battery pack.

Data Type : unsigned integer

Unit : [mV]

Nominal Available Capacity [0x0C/0x0D]

This command returns the remaining capacity of a battery.

The absolute remaining capacity is a capacity under standard conditions (0.2C discharge, 25°C).

Data Type : unsigned integer

Unit : [mAh]

Full Available Capacity [0x0E/0x0F]

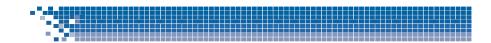
This command returns the full charge capacity.

The full charge capacity is a full capacity under standard conditions (0.2C discharge,  $25^{\circ}$ C).

Data Type : unsigned integer

Unit : [mAh]





### Remaining Capacity [0x10/0x11]

This command returns the usable capacity based on temperature and discharge current.

smoothing valid setting : Filtered RM value smoothing invalid setting : Unfiltered RM value

Data Type : unsigned integer

Unit : [mAh]

Full Charge Capacity [0x12/0x13]

This command returns the full charge capacity based on temperature and discharge current.

smoothing valid setting : Filtered FCC value smoothing invalid setting : Unfiltered FCC value

Data Type : unsigned integer

Unit : [mAh]

Average Current [0x14/0x15]

This command returns the average current which flows into a battery or out from a battery.

Data Type : signed integer

Unit : [mA]

Average Time To Empty [0x16/0x17]

This command returns operation time (usable time) from average current and temperature. If no current flows, the value calculated as default discharge is returned, and if charge current flows, a value of 65535 is returned.

Data Type : unsigned integer

Unit : [minutes]

Filtered FCC [0x18/0x19]

This command returns the usable filtered full charge capacity based on temperature and discharge current.

Data Type : unsigned integer

Unit : [mAh]





### Unfiltered FCC [0x1C/0x1D]

This command returns the usable unfiltered full charge capacity based on temperature and discharge current.

Data Type : unsigned integer

Unit : [mAh]

Max Load Current [0x1E/0x1F]

This command returns the maximum current which flows out from a battery. Max load current is updated to the measured current which is greater than the stored value or initial max load setting. And it is reseted to the average of the latest value and initial value at full charge condition.

Data Type : signed integer

Unit : [mA]

Unfiltered RM [0x20/0x21]

This command returns the usable unfiltered capacity based on temperature and discharge current. If no current flow or charge current flow, the capacity which based on defined

Data Type : unsigned integer

Unit : [mAh]

Filtered RM [0x22/0x23]

This command returns the usable filtered capacity based on temperature and discharge current. If no current flow or charge current flow, the capacity which based on defined discharge current (about 0.2C).

Data Type : unsigned integer

Unit : [mAh]

Internal Temperature [0x28/0x29]

This command returns the temperature information measured by the temperature sensor built in this IC.

Data Type : signed integer

Unit : [0.1K] ( $[0.1^{\circ}C]$  selectable by Data Flash setting)





### Cycle Count [0x2A/0x2B]

This command returns the number full charge count to the present.

When total charged capacity reaches full charge capacity, the number of full charge count will be counted up 1.

Data Type : unsigned integer

Unit : [counts]

State Of Charge [0x2C/0x2D]

This command returns the percentage of usable capacity to usable full charge capacity based on temperature and discharge current. If no current flows or charge current flows, it returns the percentage which based on defined discharge current (about 0.2C).

Data Type : unsigned integer

Unit : [%]

State Of Health [0x2E/0x2F]

This command returns the percentage of the present battery capacity to the initial battery capacity.

Data Type : unsigned integer

Unit : [%]

Passed Charge [0x34/0x35]

This command returns the amount of charge capacity from OCV after discharged.

Data Type : unsigned integer

Unit : [mAh]

DOD0 [0x36/0x37]

This command returns the depth of discharge at last OCV.

Data Type : unsigned integer

Unit : N/A

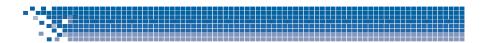
Self Discharge Current [0x38/0x39]

This command returns the self-discharge current of battery.

Data Type : signed integer

Unit : [mAh]





### Flags [0x0A/0x0B]

This command returns the battery status/information.

The battery status/information are assigned to each bit as follows.

	bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0
Hi byte	OTC	OTD	BATHI	BATLOW	CHG_INH	RSVD	FC	CHG
Lo byte	OCVTAKEN	OCC	ODC	ОТ	UT	SOC1	SOCF	DSG

OTC : Over Temperature in charge When the current is more than or equal to charge

threshold current,

More than or equal to upper temperature limit : 1 Less than or equal to recover temperature : 0

OTD : Over Temperature in discharge When the current is less than or equal to discharge

threshold current,

More than or equal to upper temperature limit: 1 Less than or equal to recover temperature: 0

Less than or equal to recover voltage: 0

BATLOW: Over-Discharge Less than or equal to lower voltage limit: 1

More than or equal to recover voltage: 0

CHG\_INI: Charge Inhibit When the current is more than or equal to charge

threshold current,

charge inhibit temperature (upper/lower limit) : 1 charge permission temperature or the current is

less than charge threshold current : 0

FC : Full Charge Full charge detection : 1

SOC < Full charge release threshold SOC: 0

Full charge detection condition

1) Voltage is more than or equal to full-charge voltage.

2) Current is less than charge termination current.

3) The condition of 1) and 2) are detected for the setting time





CHG : charge allowed SOC,

and  $CHG_INH = 0 : 1$ 

SOC is more than full charge release threshold SOC

or  $CHG_INH = 1 : 0$ 

OCVTAKEN Correct Remaining Capacity Corrected the remaining capacity by OCV: 1

not Corrected the remaining capacity by OCV: 0

OCC : Over Charge Current More than or equal to upper current limit : 1

Less than or equal to recover current :  $\ensuremath{\mathbf{0}}$ 

ODC : Over Discharge Current Less than or equal to lower current limit :  $\mathbf{1}$ 

More than or equal to recover current :  $\mathbf{0}$ 

OT : Over Temperature More than or equal to upper temperature limit : 1

Less than or equal to recover temperature :  $\mathbf{0}$ 

UT : Under Temperature Less than or equal to lower temperature limit : 1

More than or equal to recover temperature : 0

SOC1 : It shows following status by the selection of function.

<Remaining Capacity Notification Function = Valid>

SOC1 detection (Discharging) Remaining Capacity < SOC1 Set Threshold: 1

SOC1 detection (Charging) :  $1\rightarrow 0$  or  $0\rightarrow 1$ 

Remaining Capacity > SOC1 Clear Threshold

: 1→0 or 0→1

\*Set/Clear SOC1command is received : 0

<Remaining Capacity Notification Function = Invalid>

SOC1 detection Remaining Capacity ≤ SOC1 Set Threshold: 1

Remaining Capacity  $\geq$  SOC1 Clear Threshold : 0

SOCF : SOC Final detection Remaining Capacity ≤ SOCF Set Threshold : 1

Remaining Capacity ≥ SOCF Clear Threshold: 0

DSG : Discharge : 1, Charge or 0mA : 0





### Safety Status [0x1A/0x1B]

This command returns the battery status/information. It is extended function of Flags command.

The battery status/information are assigned to each bit as follows.

	bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0
Hi byte	RSVD							
Lo byte	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	OVP	UVP

Less than or equal to recover voltage: 0

UVP : Under Voltage detection Less than or equal to lower voltage limit : 1

More than or equal to recover voltage: 0

#### STANDARD COMMAND DETAIL (Group 2)

The command which transmits and receives parameter data to this IC is shown below.

#### Control [0x00/0x01]

This command returns various setting data / information of this IC, and sets various control setting. The above process is performed by the parameter which is sent 2bytes data with command.

#### Command Parameter

Table 12-4. Control Command Parameter

	Name
Byte 0	Request Code Low Byte
Byte 1	Request Code Hi Byte

#### Receive Data

Table 12-5. Control Data Format

	Name
Byte 0	Data Low Byte
Byte 1	Data Hi Byte





### [Request code list]

Table 12-6. Request code table

Request content code	Code	type	Description
CONTROL_STATUS	0x0000	R	status information
DEVICE_TYPE	0x0001	R	device type
FW_VERSION	0x0002	R	firmware version
HW_VERSION	0x0003	R	hardware version
RANK_CODE	0x0004	R	rank code information
PREV_MACWRITE	0x0007	R	previous MAC
CHEM_ID	0x0008	R	data flash ID (parameter ID)
DF_VERSION	0x000C	R	data flash revision (parameter rev.)
SET_SLEEP	0x0010	W	enable to change FULL SLEEP mode
SET_HIBERNATE	0x0011	W	enable to change HIBERNATE mode
CLEAR_HIBERNATE	0x0012	W	disable to change HIBERNATE mode
SET_SHUTDOWN	0x0013	W	enable to change SHUTDOWN mode
CLEAR_SHUTDOWN	0x0014	W	disable to change SHUTDOWN mode
OCV_CMD	0x001F	W	execute OCV correction
SEALED	0x0020	W	set SEALED access mode
IG_ENABLE	0x0021	W	enable device to normal FG operation mode
CAL_ENABLE	0x002D	W	set device to Calibration test mode
SET_LOCKTYPE	0x0040	W	set device Lock type
RESET	0x0041	W	reset device
EXIT_CAL	0x0080	W	stop device to measure Calibration
ENTER_CAL	0x0081	W	start device to measure Calibration

### CONTROL\_STATUS [0x0000]

This request code returns the various status information of the device.

	bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0
Hi byte	RSVD	FAS	SS	CALMODE	RSVD	RSVD	QMAXUPDATE	RSVD
Lo byte	SHUTDOWN	HIBERNATE	FULLSLEEP	SLEEP	LDMD	DNR	VOK	QEN

FAS : FULL ACCESS SEALED If device is Full Access Sealed (The specific area of

state Data Flash is read/write prevented) condition,

it is set to 1.

SS : SEALED / UNSEALED If device is Sealed (Data Flash is read/write

state prevented) condition, it is set to 1.

CALMODE : Calibration function If Calibration function is enabled (after CAL\_ENABLE

is sent), it is set to 1.

QMAXUPDATE: QMAX update It shows battery capacity update. It toggled by

each update.

SHUTDOWN : SHUTDOWN function If device is enabled to change SHUTDOWN mode,

it is set to 1.





HIBERNATE : HIBERNATE function If device is enabled to change STANDBY mode,

it is set to 1.

FULLSLEEP : FULL SLEEP function If device is enabled to change FULL SLEEP mode,

it is set to 1.

SLEEP : SLEEP function It shows the device is in SLEEP mode.

LDMD : Constant power/ Constant power mode : 1

Constant current algorithm

DNR : Device not Ready When FG operation mode is started, it is set to 1

until FG information is ready.

In the following cases, the device starts from DNR = 1

condition.

1) after POR, 2) after change to Normal mode from

Standby mode.

VOK : Voltage OK When device is judged voltage stable, it is set to 1.

QEN : FG mode enable When device is normal FG operation mode,

it is set to 1. (after IG\_ENABLE is sent)

DEVICE\_TYPE [0x0001]

This request code returns the type information of this IC. This IC returns "0x8118".

FW\_VERSION [0x0002]

This request code returns the firmware version.

HW\_VERSION [0x0003]

This request code returns the hardware version. This IC returns "0x0021".

RANK\_CODE [0x0004]

This request code returns the model rank code information. This IC returns "0x3047" (= 'G0').

PREV\_MACWRITE [0x0007]

This request code returns the previous value of Control command.





### CHEM\_ID [0x0008]

This request code returns ID information of battery parameter which is set in Data Flash.

#### DF\_VERSION [0x000C]

This request code returns the battery parameter version which is set in Data Flash.

#### SET\_SLEEP [0x0010]

This request code enables to change the device power mode to FULL SLEEP mode.

### SET\_HIBERNATE [0x0011]

This request code enables to change the device power mode to HIBERNATE mode.

#### CLEAR\_HIBERNATE [0x0012]

This request code disables to change the device power mode to HIBERNATE mode.

#### SET\_SHUTDOWN [0x0013]

This request code enables to change the device power mode to SHUTDOWN mode.

### CLEAR\_HIBERNATE [0x0014]

This request code disables to change the device power mode to SHUTDOWN mode.

### OCV\_CMD [0x001F]

This request code executes OCV correction by the measured voltage.

#### SEALED [0x0020]

This request code sets SEALED access mode to the device.

#### IG\_ENABLE [0x0021]

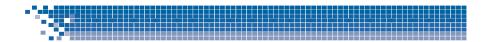
This request code enables Intelligent Gauge algorithm. And this request is only valid when the device is in UNSEALED state.

#### CAL\_ENABLE [0x002D]

This request code sets Calibration operation mode if this IC is in normal FG operation mode, and it sets normal FG operation mode if this IC is in Calibration operation mode.

And this request is only valid when it is in UNSEALED state.





### SET\_LOCKTYPE [0x0040]

This request code returns Lock type value of this IC.

RESET [0x0041]

This request code resets this IC. And this request is only valid when it is in UNSEALED state.

EXIT\_CAL [0x0080]

This request code stops the calibration process in case of Calibration operation mode. And this request is only valid when this IC is in UNSEALED state.

ENTER\_CAL [0x0081]

This request code starts the calibration process in case of Calibration operation mode. And this request is only valid when this IC is in UNSEALED state.

At Rate [0x02/0x03]

This command sets current value to calculate the operation time (usable time) at the present temperature. The calculated operation time by specified this command is available on 'At Rate Time To Empty [0x04/0x05]' command.

Command Parameter

Data Type : signed integer

Unit : [mA]

Receive Data

Data Type : signed integer

Unit : [mA]

BTP SOC1 Set [0x24/0x25]

This command sets the discharge threshold of remaining capacity, which is parameter of Remaining Capacity Notification Function.

If Remaining Capacity Notification Function is enabled, the interrupt is generated when the remaining capacity is below this discharge threshold.

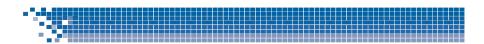
And the interrupt signal and status flag are cleared to set this command.

Command Parameter / Receive Data

Data Type : unsigned integer

Unit : [mAh]





### BTP SOC1 Clear [0x26/0x27]

This command sets the charge threshold of remaining capacity, which is parameter of Remaining Capacity Notification Function.

If Remaining Capacity Notification Function is enabled, the interrupt is generated when the remaining capacity is above this charge threshold.

And the interrupt signal and status flag are cleared to set this command.

Command Parameter / Receive Data

Data Type : unsigned integer

Unit : [mAh]

#### EXTENDED COMMAND DETAIL (Group 3)

The command which response data size is multiple bytes is shown below.

Pack Config [0x3A/0x3B]

This command returns this IC setting information of selectable function.

Those selectable settings are assigned to each bit as follows.

	bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0
Hi byte	RSVD	INTPol	INTSel	RSVD	RSVD	RSVD	RSVD	RSVD
Lo byte	RSVD	RSVD	SLEEP	RSVD	RSVD	RSVD	RSVD	TEMPS

INTPol : Polarity for Interrupt pin Low Active : 0, High Active : 1

INTSel : Interrupt pin select SE pin : 0, HDQ pin : 1

SLEEP : SLEEP function Sleep function enable : 1

Sleep function disable: 0

TEMPS : Thermistor measurement Thermistor enable : 1, Thermistor disable : 0

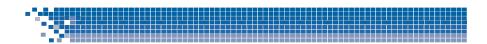
Design Capacity [0x3C/0x3D]

This command returns the design capacity of a battery.

Data Type : unsigned integer

Unit : [mAh]





#### Product Information Length [0x62]

This command returns the length of the product information data.

Data Type : unsigned char

Unit : N/A

Product Information [0x63~0x6C]

This command returns the product information.

The information data is 10bytes in binary data.

Name	Size
Device Model Name	8bytes
Reserved	2bytes

#### Current [0x72/0x73]

This command returns the measured current which flows into a battery or out from a battery.

Data Type : signed integer

Unit : [mA]

### [UNSEALED state]

Block Data Control [0x61] = 0x00:

This area is used to set/get some initial setting data and the parameter data of battery dependent to/from the specified data flash class/block.

Block Data Control  $[0x61] \neq 0x00$ :

This area is used to set authentication data.

### [SEALED state]

Data Flash Block [0x3F] = 0x00:

This area is used to set authentication data.

Data Flash Block [0x3F] = 0x01 - 0x03:

This area is used to get data of Manufacture Data A, B, C. 32bytes of memory area is available.

<In case of authentication usage>

This area is assigned to following definition.

Authenticate [0x40~0x53]

This area is used for authentication data.





#### Authenticate Checksum [0x54]

This command sets Checksum of 20bytes authentication data. The authenticate is performed by write operation.

Reserved [0x55~0x5F]

This area is not used.

Block Data Checksum [0x60]

This command sets/returns Checksum of 32bytes Block Data. In case of Read operation, it is updated at setting Class/Block value. In case of Write operation, it executes to save to Data Flash by updating latest Checksum result. In case of SEALED state, the access is

Block Data Control [0x61]

This command sets Data Flash mode. In case of SEALED state, the access is rejected.

0x00: The device is set Data Flash Access mode which set/get some initial setting data and the parameter data of battery dependent by the specified data flash class/block.

EXTENDED COMMAND DETAIL (Group 4)

The command which transmits and receives parameter data to this IC is shown below.

Data Flash Class [0x3E]

This command sets the data flash class which reads/writes some initial setting data and the parameter data of battery dependent from/to Data Flash. In case of SEALED state, the access is

Data Flash Block [0x3F]

This command sets the data flash block which reads/writes some initial setting data and the parameter data of battery dependent from/to Data Flash.

In case of UNSEALED state, this IC is set 0x00 only, not set except for 0x00.

In SEALED state, the setting for the specific purpose is permitted only.

0x00 : set authenticate data

0x01 - 0x03 : get data of Manufacture Data A - C





Block Data [0x40~0x5F]

These 32bytes memory area is used for several purpose by SEALED/UNSEALED state and Data Flash Class [0x3E], Data Flash Block [0x3F], Block Data Control [0x61] commands setting.

```
[UNSEALED state]
```

```
Block Data Control [0x61] = 0x00:
```

This area is used to set/get some initial setting data and the parameter data of battery dependent to/from the specified data flash class/block.

```
Block Data Control [0x61] \neq 0x00:
```

This area is used to set authentication data.

```
[SEALED state]
```

```
Data Flash Block [0x3F] = 0x00:
```

This area is used to set authentication data.

```
Data Flash Block [0x3F] = 0x01 - 0x03:
```

This area is used to get data of Manufacture Data A, B, C. 32bytes of memory area is available.

<In case of authentication usage>

This area is assigned to following definition.

```
Authenticate [0x40~0x53]
```

This area is used for authentication data.

Authenticate Checksum [0x54]

This command sets Checksum of 20bytes authentication data. The authenticate is performed by write operation.

Reserved [0x55~0x5F]

This area is not used.

Block Data Checksum [0x60]

This command sets/returns Checksum of 32bytes Block Data. In case of Read operation, it is updated at setting Class/Block value. In case of Write operation, it executes to save to Data Flash by updating latest Checksum result. In case of SEALED state, the access is rejected.





### Block Data Control [0x61]

This command sets Data Flash mode. In case of SEALED state, the access is rejected.

0x00 : The device is set Data Flash Access mode which set/get some initial setting

data and the parameter data of battery dependent by the specified data flash

class/block.

other: The device is set Authenticate mode.

#### FG Condition [0x6E/0x6F]

This command returns the data of the operational mode, and sets the operational mode and executes the correction process.

#### Command Parameter

Table 12-10. FG Condition Command Parameter

	Name
Byte 0	Request code
Byte 1	Parameter

#### Receive Data

Table 12-11. FG Condition Data Format

	Name
Byte 0	Operational mode
Byte 1	reserved

#### [Request code]

<Execute code>

0x00 : NORMAL mode0x01 : SLEEP mode0x02 : SHUTDOWN mode0x03 : STANDBY mode

0x20 : OCV correction (by measured Voltage)0x21 : OCV correction (by Average Voltage)0x40 : Lock Level (with parameter byte)

0x80 : System Reset request (It is valid in UNSEALED state only.)

### [Operational mode]

0x00 : NORMAL mode 0x01 : SLEEP mode 0x04 : STANDBY mode





## Data flash

#### DATA FLASH SUMMARY

summarizes the data flash locations available to the user, including their default, minimum, and maximum values.

In case of SEALED state, Manufacture A/B/C area is available to read only. The other Category area except for Security is available to read/write in UNSEALED state. Security area is available to read/write at FULL ACEESS state only.

Table 13-1. Data Flash List

Group	Category	Class	Offset	Name	Data	Min	Max	Default	Unit
	,				Type	value	Value	Value	
Configuration	Data	0x00	0x00~01	Rank Code	Cbyte	-	-	"G0"	-
			0x02 0x04	FW Version Parameter Version	Hword Hword	0x0 0x0	0xffff 0xffff	0x0800 0x0100	-
			0x04 0x06	Mask FW Parameter Version	Hword	0x0	0xffff	0x0000	_
			0x08~0f	Pack Name	Cbyte	UXU	UXIIII	UXUUUU	
			0x08701	Pack ID	Hword	0x0	0xffff	0x0	-
			0x10 0x12	Pack ID Pack sub ID	Hword	0x0	0xffff	0x0	-
	Custom	0x01	0x12 0x00				0xffff	0x0	_
	System	OXUI	0x00 0x02	PackConfigA	Hword	0x0	0xff	0x0	
				PackConfigB	Hbyte	0x0			-
			0x03	PackConfigC	Hbyte	0x0	0xff	0x0	-
			0x04	PackConfigD	Hbyte	0x0	0xff	0x0	-
			0x05	PackConfigE	Hbyte	0x0	0xff	0x0	-
			0x06	PackConfigF	Hbyte	0x0	0xff	0x0	-
			0x07	PackConfigG	Hbyte	0x0	0xff	0x0	-
			0x08	Design Voltage	Uword	0	65535	3700	mV
			0x0a	Design Capacity	Uword	0	65535	2420	mAh
			0x0c	MaxLoad Default	Sword	-32768	32767	-500	mA
			0x0e	CycleCount Default	Uword	0	65535	0	num
	Charge	0x01	0x18	Fullcharge Detect Voltage	Uword	0	65535	4350	mV
	Term		0x1a	Fullcharge Detect Voltage Window	Uword	0	65535	50	mV
			0x1c	Fullcharge Detect Current	Uword	0	65535	100	mA
			0x1e	Fullcharge Detect Time	Ubyte	0	255	60	sec
			0x1f	Fullcharge Detect Current Window	Ubyte	0	255	10	mA
	Discharge	0x02	0x00	Lower limit voltage	Uword	0	65535	3400	mV
	Term		0x02	Force SOC 0% Voltage	Uword	0	65535	2750	mV
	Current	0x02	0x11	Sleep detection time	Ubyte	0	255	60	sec
			0x12	Sleep mode Interval	Ubyte	0	255	20	sec
	Capacity	0x02	0x1c	Initial capacity	Uword	0	65535	2450	mAh
	Safety	0x03	0x00	SOC1 set threhold	Uword	0	65535	245	mAh
	,		0x02	SOC1 clear threhold	Uword	0	65535	367	mAh
			0x04	SOCF set threhold	Uword	0	65535	74	mAh
			0x06	SOCF clear threhold	Uword	0	65535	184	mAh
			0x08	Full charge flag clear threshold	Ubyte	0	255	98	%
			0x09	CHG flag set threshold	Ubyte	0	255	95	%
			0x0a	Charge Inhibit Low Limit Temperature	Sword	-32768	32767	-50	0.1°C
			0x0c	Charge Inhibit Hi Limit Temperature	Sword	-32768	32767	500	0.1°C
			0x0e	Charge Inhibit Hysteresis	Sbyte	-128	127	50	0.1°C
			0x10	Alert IO Enable	Hword	0x0	0xffff	0x0	-
			0x12	Battery Low-voltage detection	Uword	0	65535	2950	mV
			0x14	Battery Low-voltage recovery	Uword	0	65535	3100	mV
			0x16	Battery Low-voltage delay time	Ubyte	0	255	2	sec
			0x17	Battery Hi-voltage delay time	Ubyte	0	255	2	sec
			0x17	Battery Hi-voltage detection	Uword	0	65535	4400	mV
			0x1a	Battery Hi-voltage detection  Battery Hi-voltage recovery	Uword	0	65535	4300	mV
			0x1c	Discharge current	Sword	-32768	32767	-10	mA
			0x1c	Charge current	Sword	-32768	32767	10	mA
L		l	OYTE	Charge Current	JWOIG	-32/00	32/0/	10	IIIA



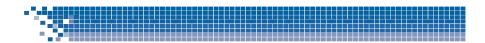


Table 13-2. Data Flash List

Safety				0x00 0x02 0x04 0x05	Hi-temperature in discharge detection Hi-temperature in discharge recovery Hi-temperature in discharge delay time	Sword Sword Ubyte	-32768 -32768	32767 32767	600 550	Unit 0.1°C 0.1°C
	Configuration	Safety	0x04	0x02 0x04 0x05	Hi-temperature in discharge recovery Hi-temperature in discharge delay time	Sword Ubyte	-32768	32767	550	
				0x04 0x05	Hi-temperature in discharge delay time	Ubyte				0.1°C
DN05				0x05			0			
Dx06										sec
Double										sec
0x0a										0.1°C
Ox0c										0.1°C
Ox06					<b>_</b>					mA
Ox0f										mA
0x10										sec
Note										sec
No.14										mA
No.   No.										mA
0x18					<u> </u>					0.1°C
										0.1°C
Note										sec
Note				<del></del>						sec
Dx05				<del></del>	•					0.1°C
					•					0.1°C
			0x05							mV
Description										mV
Description										sec
										%
Dx0a										mV
Dx0b										mV
Dx0c										sec
Dx0e										sec
LogInfo										mV
0x12					<u> </u>					mV
0x14	LogInfo	LogInfo	0x05							mV
0x15										mV
0x16										mV
0x18					•	Ubyte				mA
0x1a				0x16	Max Current initial value	Sword	-32768		0	mA
Dx1c					Min Current initial value					mA
0x1e         Update difference Temperature         Ubyte         0         255         50         0.           THMtable         THMtable         0x06         0x00~off         Thermistor input threshold[0] - [7]         Sword         -32768         32767         -           0x10~1f         Thermistor coefficient[0][0] - [2][1]         Sword         -32768         32767         -           0x07         0x00~1f         Thermistor coefficient[0][0] - [7][2]         Sword         -32768         32767         -           0x08         0x00~02         Thermistor soefficient[0][-7][2]         Ubyte         0         255         -           0x03         Thermistor function setting         Hbyte         0x0         0xff         0xff           OCV         OCV         0x0b         0x02         NoOcvVoltage         Uword         0         65535         0         r				0x1a	Max Temperature initial value	Sword			150	0.1°C
Description   Column   Colu				0x1c	Min Temperature initial value	Sword	-32768	32767	350	0.1°C
THMtable         THMtable         0x06         0x00~0f         Thermistor input threshold[0] - [7]         Sword         -32768         32767         -           0x10~1f         Thermistor coefficient[0][0] - [2][1]         Sword         -32768         32767         -           0x07         0x00~1f         Thermistor coefficient[2][2] - [7][2]         Sword         -32768         32767         -           0x08         0x00~02         Thermistor shift coefficient[0] - [2]         Ubyte         0         255         -           0x0         0x03         Thermistor function setting         Hbyte         0x0         0xff         0xff           OCV         OCV         0x0b         0x02         NoOcvVoltage         Uword         0         65535         0         r				0x1e	Update difference Temperature	Ubyte	0	255	50	0.1°C
0x10~1f         Thermistor coefficient[0][0] - [2][1]         Sword         -32768         32767         -           0x07         0x00~1f         Thermistor coefficient[2][2] - [7][2]         Sword         -32768         32767         -           0x08         0x00~02         Thermistor shift coefficient[0] - [2]         Ubyte         0         255         -           0x0         0x03         Thermistor function setting         Hbyte         0x0         0xff         0xff           OCV         OCV         0x0b         0x02         NoOcvVoltage         Uword         0         65535         0         r				0x1f	Update minimum interval	Ubyte	0	255	20	sec
0x07         0x00~1f         Thermistor coefficient[2][2] - [7][2]         Sword         -32768         32767         -           0x08         0x00~02         Thermistor shift coefficient[0] - [2]         Ubyte         0         255         -           0x03         Thermistor function setting         Hbyte         0x0         0xff         0xff           OCV         OCV         0x0b         0x02         NoOcvVoltage         Uword         0         65535         0         r	THMtable	THMtable	0x06	0x00~0f	Thermistor input threshold[0] - [7]	Sword	-32768	32767	-	-
0x08         0x00~02         Thermistor shift coefficient[0] - [2]         Ubyte         0         255         -           0x03         Thermistor function setting         Hbyte         0x0         0xff         0xff           OCV         OCV         0x0b         0x02         NoOcvVoltage         Uword         0         65535         0         r									-	-
OCV         OCV         0x0b         0x02         NoOcvVoltage         Uword         0         65535         0         r									-	-
OCV OCV 0x0b 0x02 NoOcvVoltage Uword 0 65535 0 r			0x08				0		-	-
										-
0x04   NoOcvVoltRange   Ubyte   0   255   0   r	OCV	ocv	0x0b							mV
					NoOcvVoltRange	Ubyte		255		mV
		RCAP	0x0b							%
										%
		OCVtable							-	mV
			0x0d						-	mV
0x18~1f									-	-
0x0e 0x00~1f OcvSoc[4] - [19] Hword 0x0 0xffff -									-	-
Security   Codes   0x0f   0x00   Seal to Unseal code[0]   Hword   0x0   0xffff   0x1234	Security	Codes	0x0f							-
0x02         Seal to Unseal code[1]         Hword         0x0         0xffff         0x5678									0x5678	-
	Lifetime	Lifetime	0x70						-	mV
					<u> </u>				-	mV
									-	count
			1		BatLoAlertCount	Ubyte			-	count
				0x06		Sword	-32768	32767	-	mA
0x08 MinCurrent Sword -32768 32767 - r	1			0x08	MinCurrent	Sword	-32768	32767	-	mA
0x0a OverChgCurrCount Ubyte 0 255 - cc				0x0a	OverChgCurrCount	Ubyte	0	255	-	count
									-	count
0x0c MaxTemperature Sword -32768 32767 - 0.				0x0c	MaxTemperature	Sword	-32768	32767	-	0.1°C
			I			Sword			-	0.1°C
0x10 OverTempCount Ubyte 0 255 - cc			1							
0x11         UnderTempCount         Ubyte         0         255         -         cc						Ubyte		255	-	count





Table 13-3. Data Flash List

Group	Category	Class	Offset	Name	Data Type	Min value	Max Value	Default Value	Unit
User	User Calib	0xf1	0x00	Correction Factor Flag		0x0	0xffff	0xffff	-
Calibration			0x04	V-Gain	Sbyte	-128	127	-1	-
			0x05	V-Offset	Sbyte	-128	127	-1	1
			0x06	T-Gain	Sbyte	-128	127	-1	
			0x07	T-Offset	Sbyte	-128	127	-1	1
			0x08	THM-Gain	Sbyte	-128	127	-1	-
			0x09	THM-Offset	Sbyte	-128	127	-1	-
			0x0a	I-Gain	Sword	-32768	32767	-1	1
			0x0c	I-Offset	Sword	-32768	32767	-1	-
User NVM	Manufacture	0xf2	0x00~1f	ManufactureA[0] - [31]	Hbyte	0x0	0xff	0xff	
		0xf3	0x00~1f	ManufactureB[0] - [31]	Hbyte	0x0	0xff	0xff	-
		0xf4	0x00~1f	ManufactureC[0] - [31]	Hbyte	0x0	0xff	0xff	-

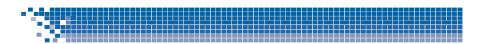
Access mode

This IC provides three kind of security modes to control the internal memory access permission

Table 13-4. Data Flash Access

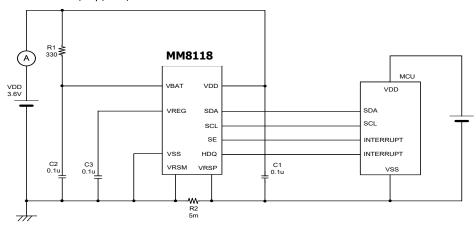
	Security mode	Manufacture A/B/C	Data Flash	Security						
	SEALED	Read	None	None						
	UNSEALED	Read/Write	Read/Write	None						
ĺ	FULL ACCESS	Read/Write	Read/Write	Read/Write						



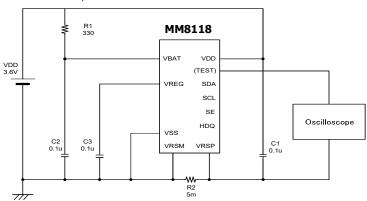


### Test circuit

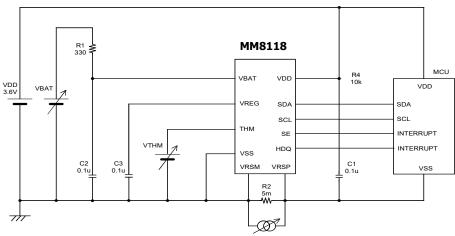
T1: Inor,Islp,Istb,Isdn



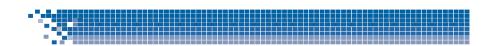
T2: fosc1,fosc2

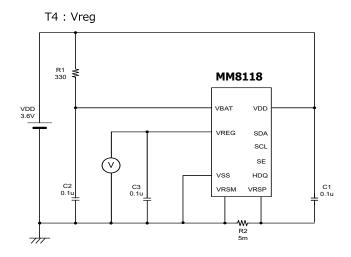


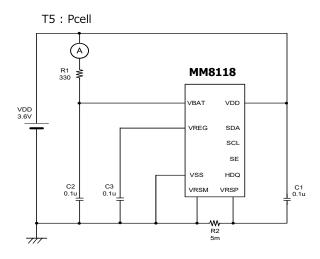
T3: Irng,Vrng,Trng,Igerr,Vgerr,Tgerr

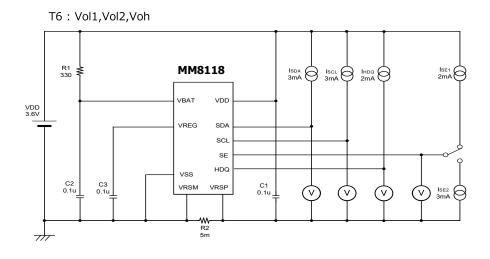






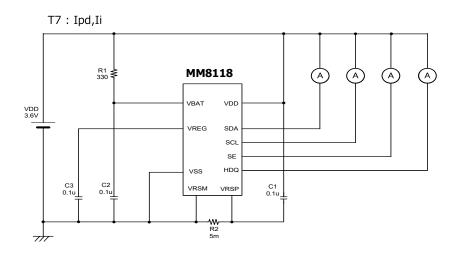


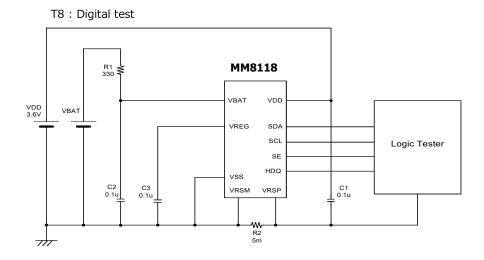




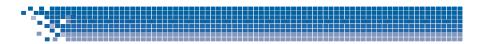




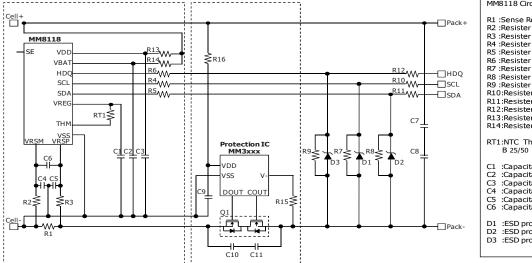








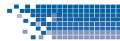
### Typical application circuit



| MM8118 Circuit Parts | R1 : Sense Resister |  $5m\Omega \pm 1\%$  | R2 : Resister |  $100\Omega \pm 5\%$  | R3 : Resister |  $100\Omega \pm 5\%$  | R4 : Resister |  $100\Omega \pm 5\%$  | R5 : Resister |  $100\Omega \pm 5\%$  | R6 : Resister |  $100\Omega \pm 5\%$  | R6 : Resister |  $100\Omega \pm 5\%$  | R8 : Resister |  $100\Omega \pm 5\%$  | R8 : Resister |  $100\Omega \pm 5\%$  | R8 : Resister |  $10\Omega \pm 5\%$  | R1 : Resister |  $10\Omega \pm 5\%$  | R1 : Resister |  $10\Omega \pm 5\%$  | R11 : Resister |  $100\Omega \pm 5\%$  | R12 : Resister |  $100\Omega \pm 5\%$  | R13 : Resister |  $100\Omega \pm 5\%$  | R14 : Resister |  $100\Omega \pm 5\%$  | R15 : Resister |  $100\Omega \pm 5\%$  | R16 : Resister |  $100\Omega \pm 5\%$  | R17 : NTC Thermistor |  $100\Omega \pm 5\%$  | R17 : NTC Thermistor |  $100\Omega \pm 5\%$  | R17 : NTC Thermistor |  $100\Omega \pm 5\%$  | R17 : NTC Thermistor |  $100\Omega \pm 5\%$  | R16 : Capacitance |  $0.47uF \pm 10\%$  | C3 : Capacitance |  $0.1uF \pm 10\%$  | C3 : Capacitance |  $0.1uF \pm 10\%$  | C5 : Capacitance |  $0.1uF \pm 10\%$  | C6 : Capacitance |  $0.1uF \pm 10\%$  | C7 : ESD protection | Glode | 0.56 | D1 : ESD protection | Glode | 0.56 | D3 : ESD protection | Glode | 0.56 | D3 : ESD protection | Glode | 0.56 | D3 : ESD protection | Glode | 0.56 | D3 : ESD protection | Glode | 0.56 | D3 : ESD protection | Glode | 0.56 | D3 : ESD protection | Glode | 0.56 | D3 : ESD protection | Glode | 0.56 | D3 : ESD protection | Glode | 0.56 | D3 : ESD protection | Glode | 0.56 | D3 : ESD protection | Glode | 0.56 | D3 : ESD | POTECTION | Glode | 0.56 | D3 : ESD | POTECTION | Glode | 0.56 | D3 : ESD | POTECTION | Glode | 0.56 | D3 : ESD | POTECTION | Glode | 0.56 | D3 : ESD | POTECTION | Glode | 0.56 | D3 : ESD | POTECTION | Glode | 0.56 | D3 : ESD | POTECTION | Glode | 0.56 | D3 : ESD | POTECTION | Glode | 0.56 | D3 : ESD | POTECTION | Glode | 0.56 | D3 : ESD | POTECTION | Glode | 0.56 | D3 : ESD | POTECTION | Glode | 0.56 | D3 : ESD | POTECTION | Glode | 0.56 | D3 : ESD | POTECTION | Glode | 0.56 | D3 : ESD | POTECTION | Glode | 0.56 | D3 : ESD | POTECTION | Glode | 0.56 | D3 : ESD | POTECTION | Glode | 0.56 | D4 : POTECTION | D3 : POTECTION | D3 :

Example of the battery pack side loading





### Package dimensions

PACKAGE:PLP-12A

